

isc Silicon NPN Power Transistor
BUR50
DESCRIPTION

- Collector-Emitter Sustaining Voltage-
: $V_{CEO(SUS)} = 125V(\text{Min})$
- High Current Capability
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

APPLICATIONS

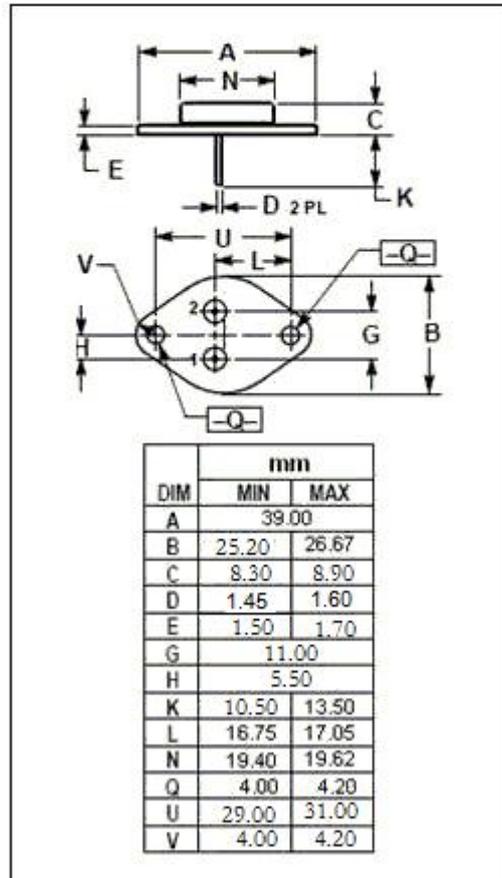
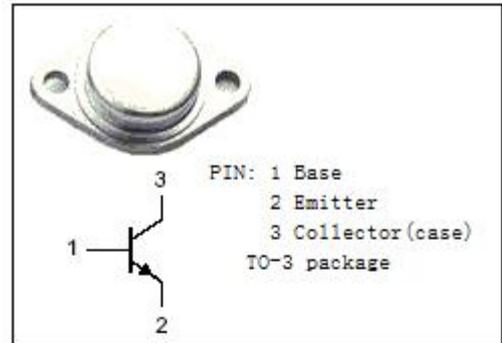
- Designed for low voltage ,high speed,power switching in Inductive circuits where fall time is critical.It is particularly suited for battery switch mode application such as switching regulations.

ABSOLUTE MAXIMUM RATINGS($T_a=25^\circ\text{C}$)

SYMBOL	PARAMETER	VALUE	UNIT
V_{CBO}	Collector-Base Voltage	200	V
V_{CEO}	Collector-Emitter Voltage	125	V
V_{EBO}	Emitter-Base Voltage	7	V
I_C	Collector Current-Continuous	70	A
I_B	Base Current-Continuous	20	A
P_C	Collector Power Dissipation @ $T_c=25^\circ\text{C}$	350	W
T_J	Junction Temperature	-65~200	$^\circ\text{C}$
T_{stg}	Storage Temperature	-65~200	$^\circ\text{C}$

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
$R_{th\ j-c}$	Thermal Resistance,Junction to Case	0.5	$^\circ\text{C/W}$



isc Silicon NPN Power Transistor**BUR50****ELECTRICAL CHARACTERISTICS** $T_C=25^{\circ}\text{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
$V_{CEO(SUS)}$	Collector-Emitter Sustaining Voltage	$I_C=50\text{mA}$; $I_B=0$	125			V
$V_{CE(sat)-1}$	Collector-Emitter Saturation Voltage	$I_C=35\text{A}$; $I_B=2\text{A}$			1.0	V
$V_{CE(sat)-2}$	Collector-Emitter Saturation Voltage	$I_C=70\text{A}$; $I_B=7\text{A}$			1.2	V
$V_{BE(sat)-1}$	Base-Emitter Saturation Voltage	$I_C=35\text{A}$; $I_B=2\text{A}$			1.8	V
$V_{BE(sat)-2}$	Base-Emitter Saturation Voltage	$I_C=70\text{A}$; $I_B=7\text{A}$			2.0	V
I_{CEO}	Collector Cutoff Current	$V_{CE}=125\text{V}$; $I_B=0$			1.0	mA
I_{CBO}	Collector Cutoff Current	$V_{CB}=200\text{V}$; $I_E=0$ $V_{CB}=200\text{V}$; $I_E=0$; $T_C=125^{\circ}\text{C}$			0.2 2	mA
I_{EBO}	Emitter Cutoff Current	$V_{EB}=7\text{V}$; $I_C=0$			0.2	mA
h_{FE-1}	DC Current Gain	$I_C=5\text{A}$; $V_{CE}=4\text{V}$	20			
h_{FE-2}	DC Current Gain	$I_C=50\text{A}$; $V_{CE}=4\text{V}$	15			

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